

PATENT APPLICATION
Sheet 1 of 2

FORM PTO-1449 LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)	ATTY. DOCKET NO. 10016150-9	APPLICATION NO. 10825754	CONFIRMATION NO.
	APPLICANT Chen et al		
	FILING DATE Herewith	GROUP	

REFERENCE DESIGNATION U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	PUBLICATION DATE	NAME	Pages, Columns, Lines Where Relevant Passages or Figures Appear
ATP	1A	5,413,513	May 1995	Horne et al	
ATP	1B	5,658,832	Aug 1997	Bernhardt et al	
ATP	1C	5,232,549	Aug 03, 1993	Cathey	
ATP	1D	6,153,978	Nov 28, 2000	Okamoto	
ATP	1E	6,137,213	Oct 24, 2000	Moyer et al	
ATP	1F	6,137,212	Oct 24, 2000	Liu et al	
ATP	1G	6,096,570	Aug 01, 2000	Hattori	
ATP	1H	6,008,576	Dec 28, 1999	Nakatani et al	
ATP	1I	5,877,594	Mar 02, 1999	Miyano et al	
ATP	1J	5,557,596	Sep 17, 1996	Gibson et al	
ATP	1K	5,541,473	Jul 30, 1996	Duboc, Jr et al	


FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	PUBLICATION DATE	NAME OF PATENTEE OR APPLICANT	Pages/Columns/Lines Where Relevant Passages/Figures Appear	Check if Translation attached
ATP	1L	EP 0559156	9-1993	Micron Technology		
ATP	1M	EP 0289278	11-1988	Canon Kabushiki		
	1N					
	1O					
	1P					

N/A
11-3-06

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)

ATP	1Q	Lee, Jin Ho et al "Fabrication and characterization of silicon field emitter arrays with focusing electrode by the chemical mechanical polishing process." J. Vac. Sci. Technol B 16(2), Mar/Apr 1998, 811-814
ATP	1R	Endo, Yasuhiro et al " Microelectron gun with silicon field emitter", J. Vac. Sci Technol. B 16(6), Nov/Dec 1998, 3082-3085
ATP	1S	Itoh, Junji et al, "Fabrication of double-gated Si field emitter arrays for focused electron beam generation" J. Vac Sci. Technol. B 13(5), Sep/Oct 1995, 1968-1972

EXAMINER 	DATE CONSIDERED 9/27/06
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